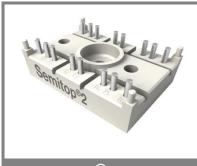
SK 75 TAA



SEMITOP[®]2

Two separated thyristors

SK 75 TAA

Target Data

Features

- Compact design
- One screw mounting
- Heat transfer and isolation through direct copper bonded aluminium oxide ceramic (DBC)
- Glass passivated thyristor chips
- Up to 1600 reverse voltage
- High surge currents

Typical Applications

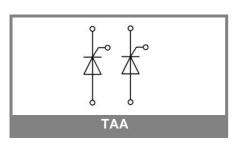
- Brake chopper
- Soft starters

V _{RSM}	V _{RRM} , V _{DRM}	I _T = 75 A
V	V	(T _s = 80 °C)
900	800	SK75TAA08
1300	1200	SK75TAA12
1700	1600	SK75TAA16

Ts = 25°C unless otherwise specified

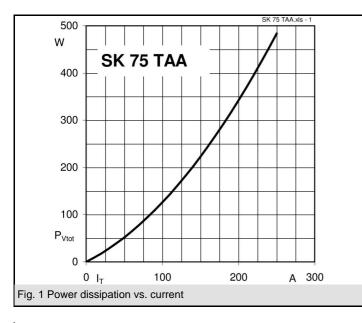
Characteristics Symbol Conditions

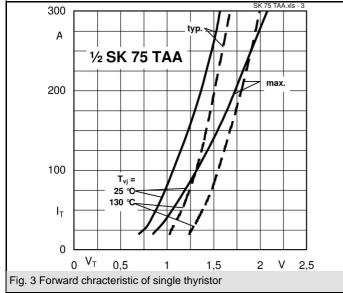
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	Symbol	Conditions	Values	Units
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	I _T	Ts = 100°C	47	А
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	I _T	Ts = 80°C	75	А
$\begin{array}{c c c c c c c c c c c c c c c c c c c $				А
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	I _{TSM} /I _{FSM}	T _{vi} = 25 (125) °C; 10 ms	1500 (1350)	A
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	l²t	T _{vi} = 25 (125) °C; half sine wave, 10 ms	11250 (9100)	A²s
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	T _{sta}		-40 + 125	°C
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	T _{solder}	terminals, 10 s	260	°C
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $	Thyristo	r		
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$			1000	V/µs
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	(di/dt) _{cr}	T _{vi} = 125 °C; f = 50 60 Hz	50	A/µs
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	ta	T _{vi} = 125 °C; typ.	80	μs
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$		T _{vi} = 25 °C; typ. / max.	100 / 200	mA
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$.,	200 / 500	mA
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$		$T_{vi} = 25 \text{ °C;} (I_T = 200 \text{ A}); \text{ max.}$	1,8	V
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$			max. 0,9	V
		$T_{vi}^{vj} = 125 \ ^{\circ}C$	max. 4,5	mΩ
		$T_{ij}^{v} = 125 \text{ °C}; V_{DD} = V_{DDM}; V_{DD} = V_{DDM}$	max. 20	mA
		cont. per thyristor	0.6	K/W
	T		,	
	V _{or}	T . = 25 °C: d.c.		
			100	mA
		$T_{v_i} = 125 \text{ °C; d.c.}$		
		,		mA
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	Diode			
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	VF	$T_{vi} = {}^{\circ}C; (I_{F} = A); max.$		V
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$				V
$ \begin{array}{c c} T_{vj} = ^{\circ}C; V_{RD} = V_{RRM} & mA \\ \hline R_{th(j-s)} & & & & & & & \\ T_{vj} & & & & & & \\ \hline \textbf{Mechanical data} & & & & & \\ \hline \textbf{Mechanical data} & & & & \\ \hline V_{isol} & AC 50Hz, r.m.s. 1min (1sec) & 2500 (3000) & V \\ \hline \textbf{M}_1 & & & & & \\ \textbf{w} & & & & & 19 & g \\ \hline \end{array} $				mΩ
R _{th(j-s)} T _{vj} K/W String °C Mechanical data °C Visol AC 50Hz, r.m.s. 1min (1sec) 2500 (3000) V M1 mounting torque 2 Nm W 19 g		.,		mA
T _{vj} °C Mechanical data V _{isol} V _{isol} AC 50Hz, r.m.s. 1min (1sec) 2500 (3000) V M1 mounting torque 2 Nm W 19 g	R _{th(j-s)}			K/W
V _{isol} AC 50Hz, r.m.s. 1min (1sec) 2500 (3000) V M1 mounting torque 2 Nm w 19 g				°C
M ₁ mounting torque 2 Nm w 19 g	Mechan	ical data	•	
M ₁ mounting torque 2 Nm w 19 g	V _{isol}	AC 50Hz, r.m.s. 1min (1sec)	2500 (3000)	V
	M ₁	mounting torque	2	Nm
Case SEMITOP [®] 2 T 81	w		19	g
	Case	SEMITOP [®] 2	T 81	

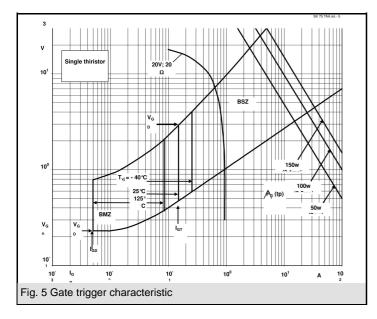


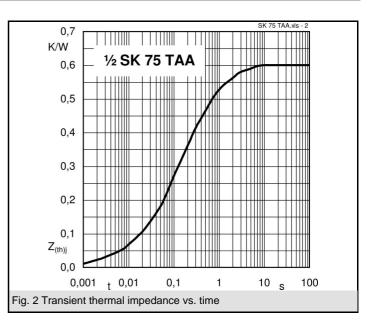
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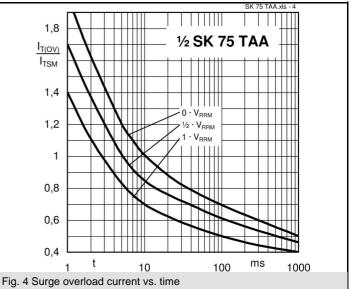
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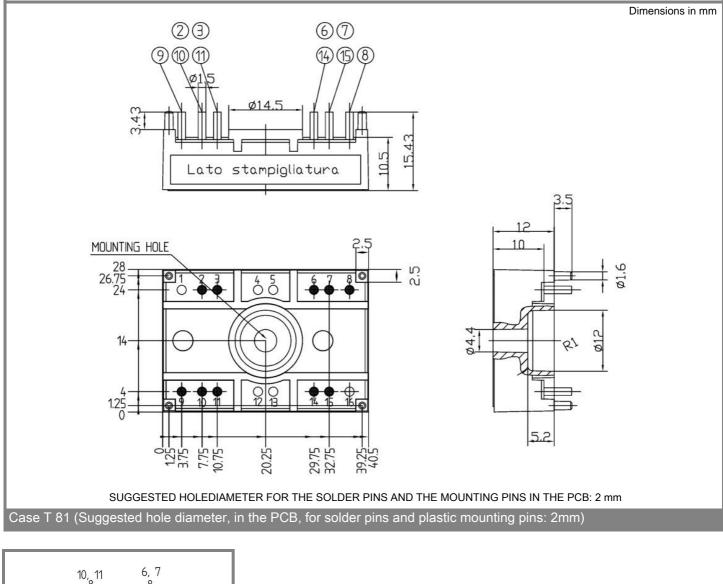


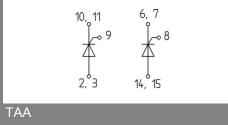






SK 75 TAA





This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

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